NSN 5961-00-162-1819

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-162-1819 **Inclosure Material:** Metal **Overall Length:** 0.540 inches **Overall Height:** 0.190 inches **Overall Width:** 0.420 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 1.00 milliamperes source cutoff current and 3.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 320.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No